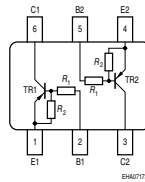
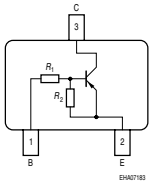


**PNP Silicon Digital Transistor**

- Switching circuit, inverter, interface circuit, driver circuit
- Built in bias resistor ( $R_1 = 22k\Omega$  ,  $R_2 = 22k\Omega$  )
- For 6-PIN packages: two (galvanic) internal isolated transistors with good matching in one package


**BCR191/F/L3**  
**BCR191T/W**
**BCR191S**  
**SEMB1**


Type	Marking	Pin Configuration						Package
		1=B	2=E	3=C	-	-	-	
BCR191	W0s	1=B	2=E	3=C	-	-	-	SOT23
BCR191F	W0s	1=B	2=E	3=C	-	-	-	TSFP-3
BCR191L3	W0	1=B	2=E	3=C	-	-	-	TSLP-3-4
BCR191S	W0s	1=E1	2=B1	3=C2	4=E2	5=B2	6=C1	SOT363
BCR191T	W0s	1=B	2=E	3=C	-	-	-	SC75
BCR191W	W0s	1=B	2=E	3=C	-	-	-	SOT323
SEMB1	W0	1=E1	2=B2	3=C2	4=E2	5=B2	6=C1	SOT666

**Maximum Ratings**

Parameter	Symbol	Value	Unit
Collector-emitter voltage	$V_{CEO}$	50	V
Collector-base voltage	$V_{CBO}$	50	
Emitter-base voltage	$V_{EBO}$	10	
Input on voltage	$V_{i(on)}$	30	
Collector current	$I_C$	100	mA
Total power dissipation- BCR191, $T_S \leq 102^\circ\text{C}$ BCR191F, $T_S \leq 128^\circ\text{C}$ BCR191L3, $T_S \leq 135^\circ\text{C}$ BCR191S, $T_S \leq 115^\circ\text{C}$ BCR191T, $T_S \leq 109^\circ\text{C}$ BCR191W, $T_S \leq 124^\circ\text{C}$ SEMB1, $T_S \leq 75^\circ\text{C}$	$P_{tot}$	200 250 250 250 250 250 250	mW
Junction temperature	$T_j$	150	°C
Storage temperature	$T_{stg}$	150 ... -65	

**Thermal Resistance**

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>1)</sup>	$R_{thJS}$		K/W
BCR191		≤ 240	
BCR191F		≤ 90	
BCR191L3		≤ 60	
BCR191S		≤ 140	
BCR191T		≤ 165	
BCR191W		≤ 105	
SEMB1		≤ 300	

<sup>1)</sup>For calculation of  $R_{thJA}$  please refer to Application Note Thermal Resistance

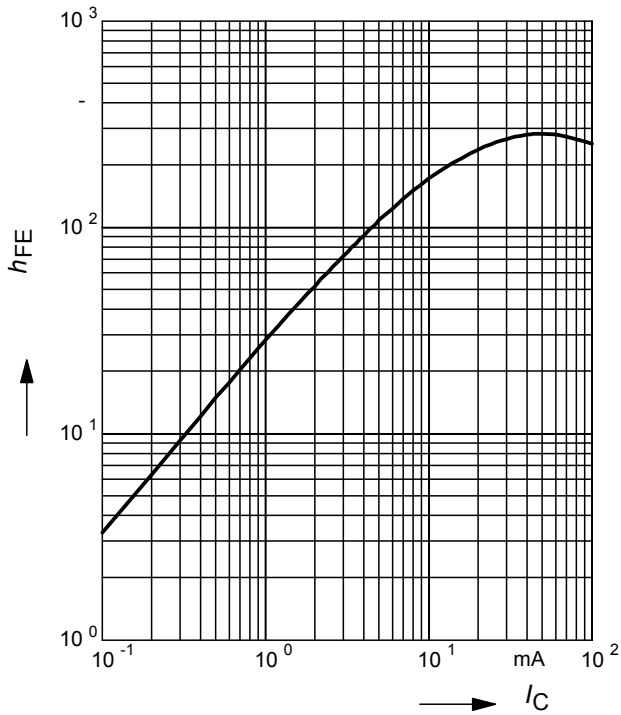
**Electrical Characteristics at  $T_A = 25^\circ\text{C}$ , unless otherwise specified**

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
<b>DC Characteristics</b>					
Collector-emitter breakdown voltage $I_C = 100 \mu\text{A}, I_B = 0$	$V_{(BR)CEO}$	50	-	-	V
Collector-base breakdown voltage $I_C = 10 \mu\text{A}, I_E = 0$	$V_{(BR)CBO}$	50	-	-	
Collector-base cutoff current $V_{CB} = 40 \text{ V}, I_E = 0$	$I_{CBO}$	-	-	100	nA
Emitter-base cutoff current $V_{EB} = 10 \text{ V}, I_C = 0$	$I_{EBO}$	-	-	350	$\mu\text{A}$
DC current gain <sup>1)</sup> $I_C = 5 \text{ mA}, V_{CE} = 5 \text{ V}$	$h_{FE}$	50	-	-	-
Collector-emitter saturation voltage <sup>1)</sup> $I_C = 10 \text{ mA}, I_B = 0,5 \text{ mA}$	$V_{CEsat}$	-	-	0,3	V
Input off voltage $I_C = 100 \mu\text{A}, V_{CE} = 5 \text{ V}$	$V_{i(off)}$	0,8	-	1,5	
Input on voltage $I_C = 2 \text{ mA}, V_{CE} = 0,3 \text{ V}$	$V_{i(on)}$	1	-	2,5	
Input resistor	$R_1$	15	22	29	$\text{k}\Omega$
Resistor ratio	$R_1/R_2$	0,9	1	1,1	-
<b>AC Characteristics</b>					
Transition frequency $I_C = 10 \text{ mA}, V_{CE} = 5 \text{ V}, f = 100 \text{ MHz}$	$f_T$	-	200	-	MHz
Collector-base capacitance $V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}$	$C_{cb}$	-	3	-	pF

<sup>1)</sup>Pulse test:  $t < 300 \mu\text{s}$ ;  $D < 2\%$

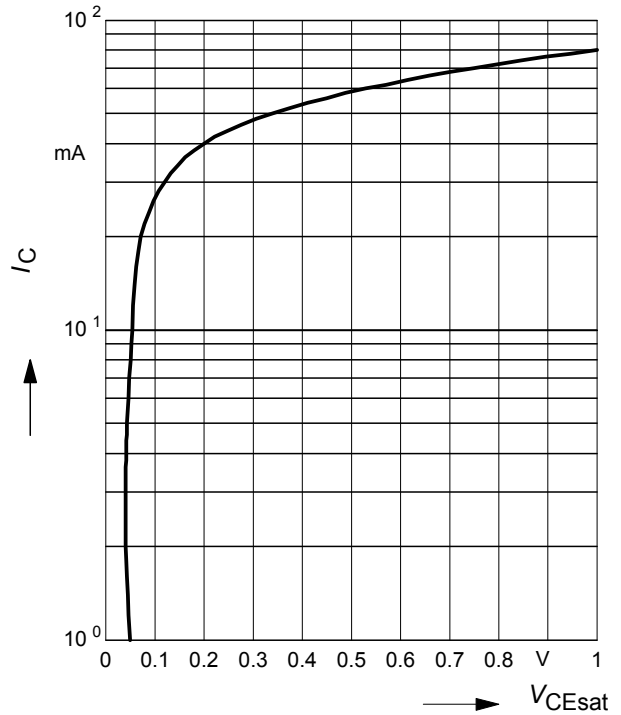
**DC current gain  $h_{FE} = f(I_C)$**

$V_{CE} = 5\text{ V}$  (common emitter configuration)



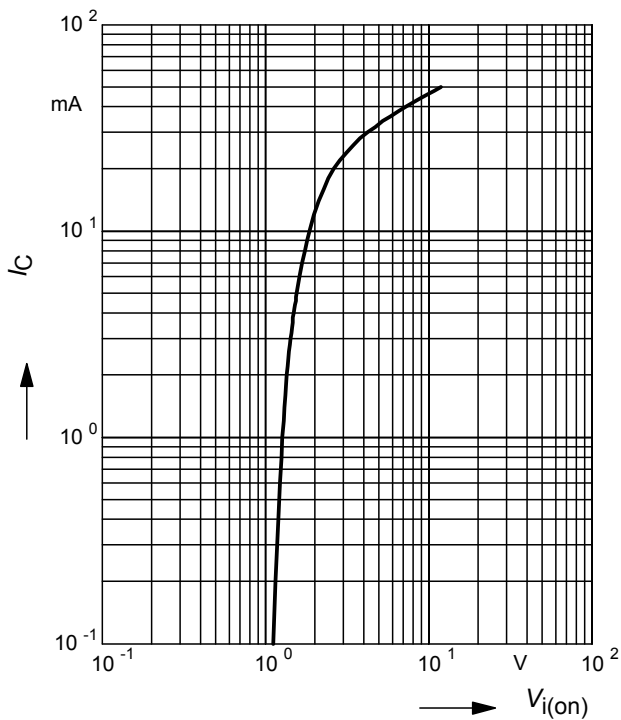
**Collector-emitter saturation voltage**

$V_{CEsat} = f(I_C), h_{FE} = 20$



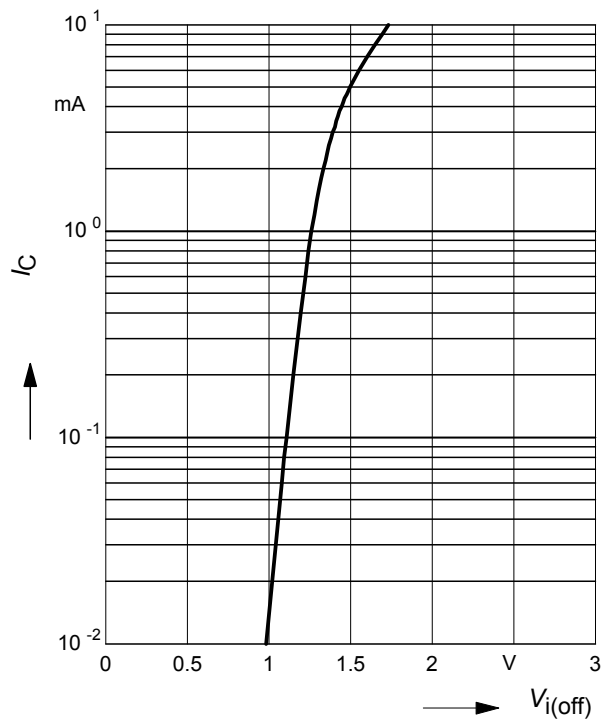
**Input on Voltage  $V_{i(on)} = f(I_C)$**

$V_{CE} = 0.3\text{ V}$  (common emitter configuration)



**Input off voltage  $V_{i(off)} = f(I_C)$**

$V_{CE} = 5\text{ V}$  (common emitter configuration)



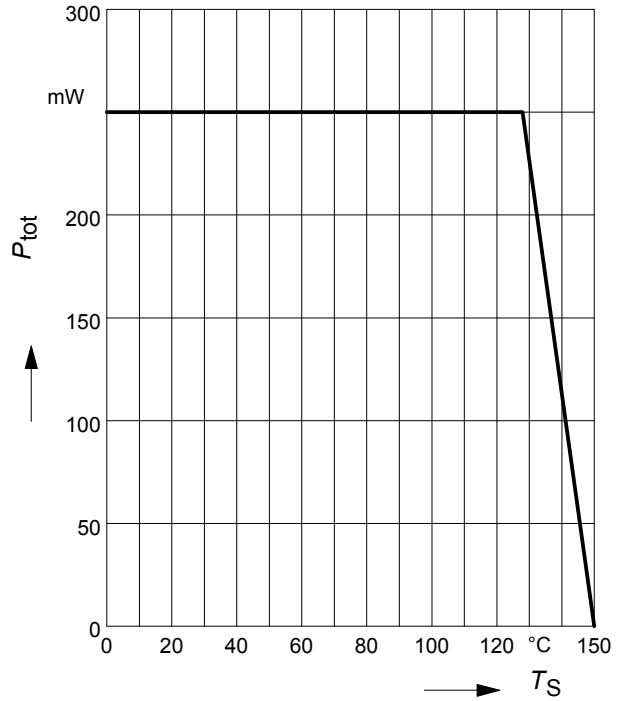
**Total power dissipation  $P_{tot} = f(T_S)$**

BCR191



**Total power dissipation  $P_{tot} = f(T_S)$**

BCR191F



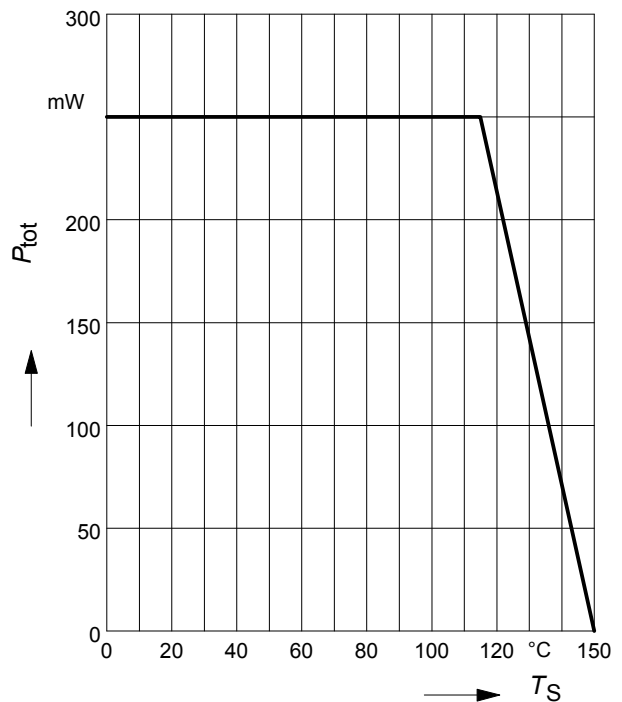
**Total power dissipation  $P_{tot} = f(T_S)$**

BCR191L3



**Total power dissipation  $P_{tot} = f(T_S)$**

BCR191S



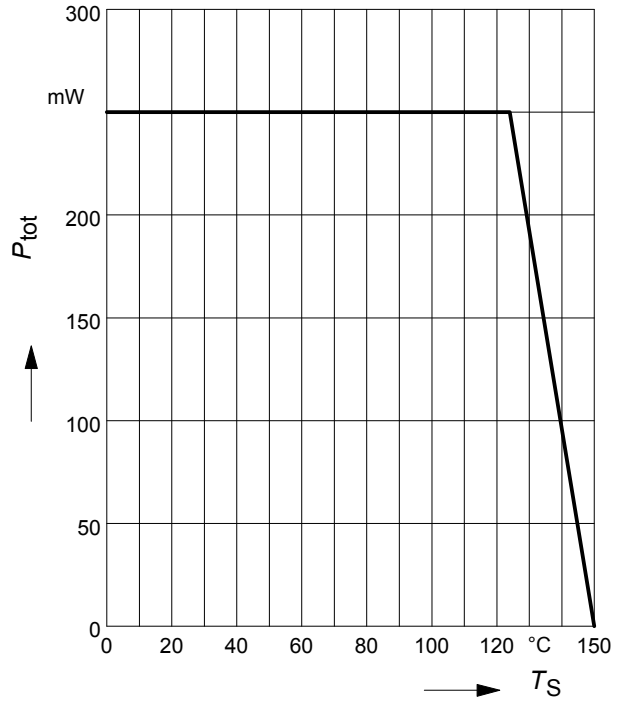
**Total power dissipation  $P_{tot} = f(T_S)$**

**BCR191T**



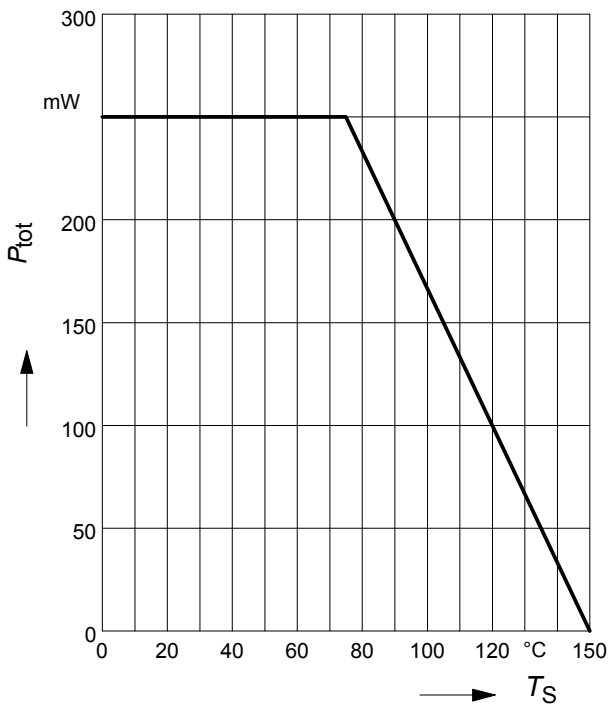
**Total power dissipation  $P_{tot} = f(T_S)$**

**BCR191W**



**Total power dissipation  $P_{tot} = f(T_S)$**

**SEMB1**



**Permissible Pulse Load  $R_{thJS} = f(t_p)$**

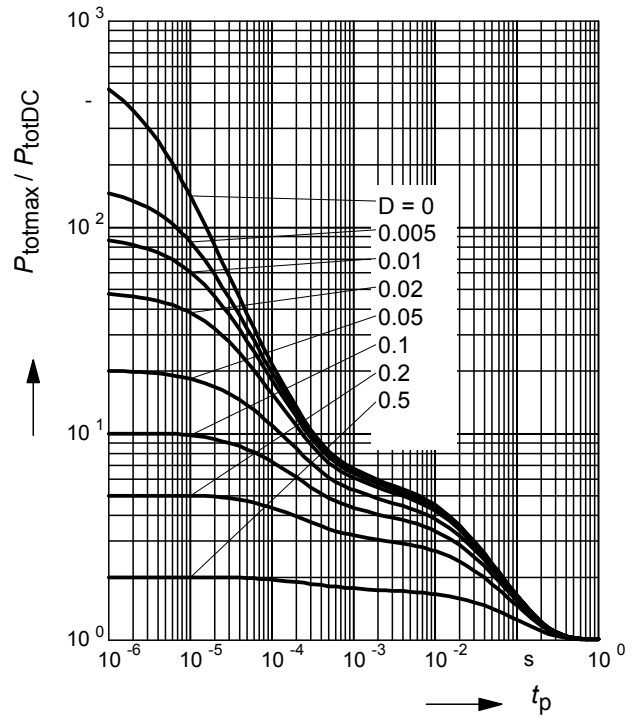
BCR191



**Permissible Pulse Load**

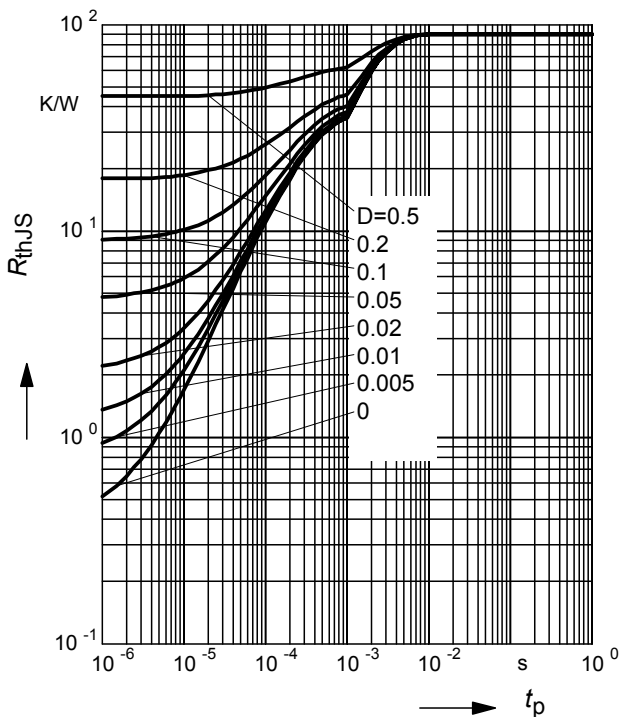
$P_{totmax}/P_{totDC} = f(t_p)$

BCR191



**Permissible Puls Load  $R_{thJS} = f(t_p)$**

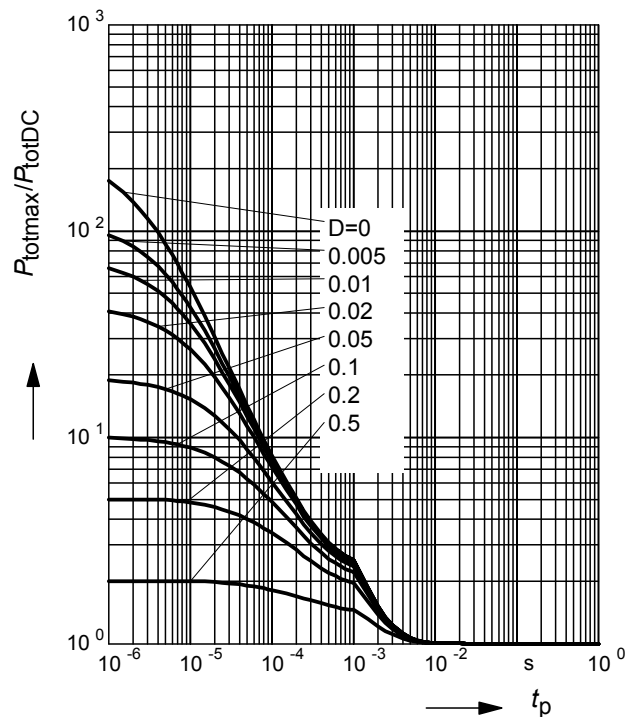
BCR191F



**Permissible Pulse Load**

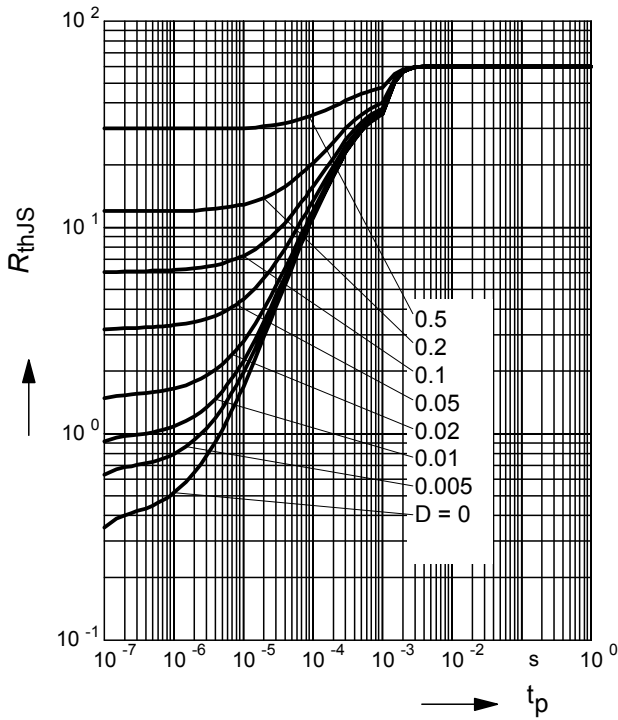
$P_{totmax}/P_{totDC} = f(t_p)$

BCR191F



**Permissible Puls Load  $R_{thJS} = f(t_p)$**

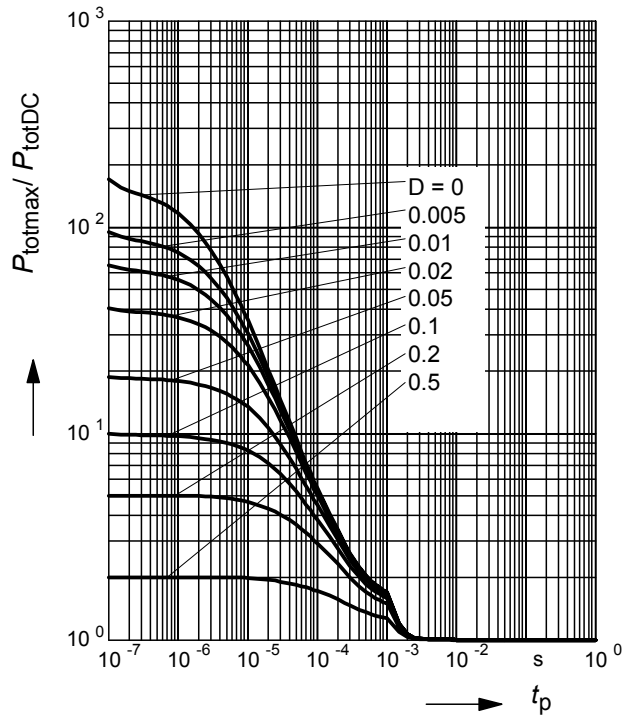
BCR191L3



**Permissible Pulse Load**

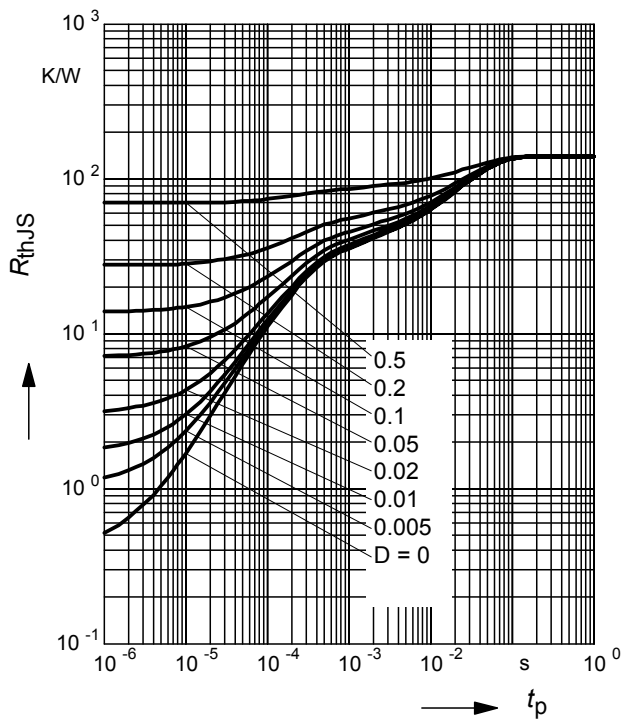
$P_{totmax}/P_{totDC} = f(t_p)$

BCR191L3



**Permissible Puls Load  $R_{thJS} = f(t_p)$**

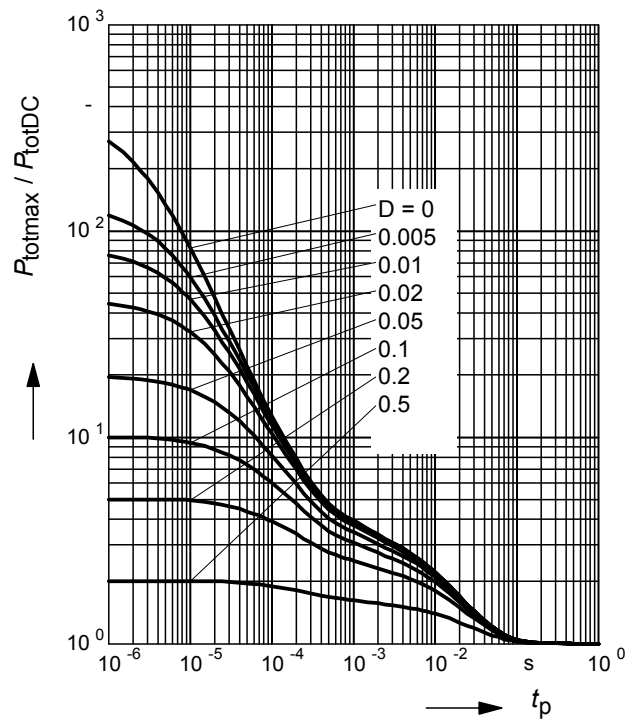
BCR191S



**Permissible Pulse Load**

$P_{totmax}/P_{totDC} = f(t_p)$

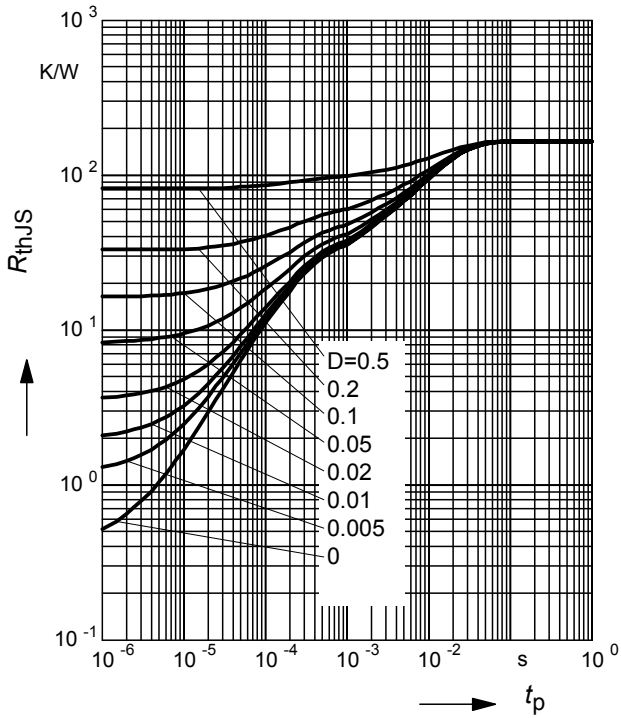
BCR191S





**Permissible Puls Load  $R_{thJS} = f(t_p)$**

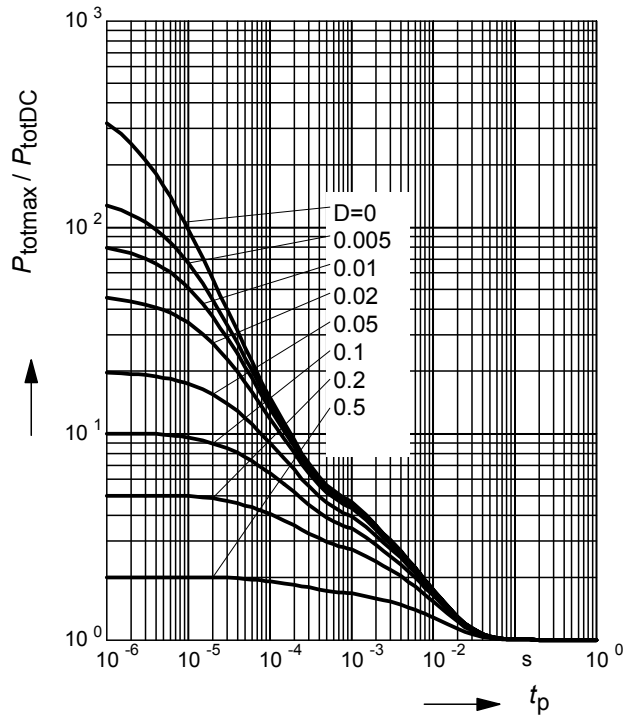
BCR191T



**Permissible Pulse Load**

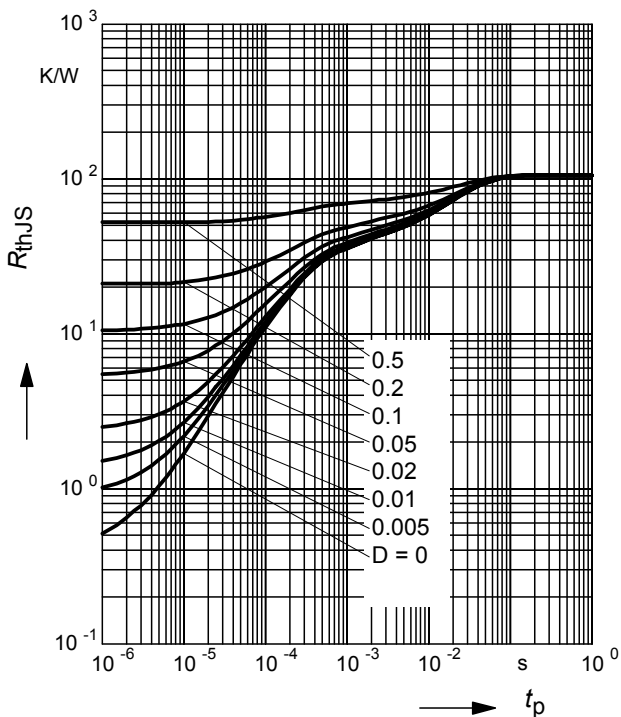
$P_{totmax}/P_{totDC} = f(t_p)$

BCR191T



**Permissible Puls Load  $R_{thJS} = f(t_p)$**

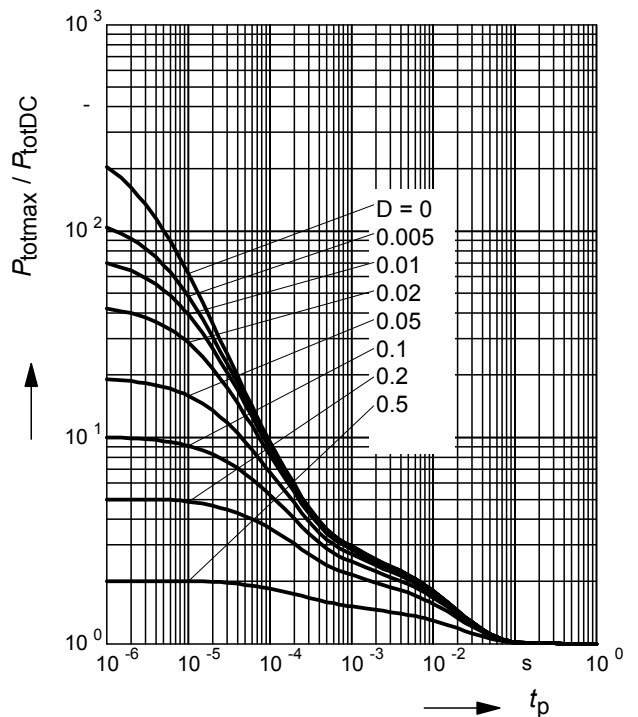
BCR191W



**Permissible Pulse Load**

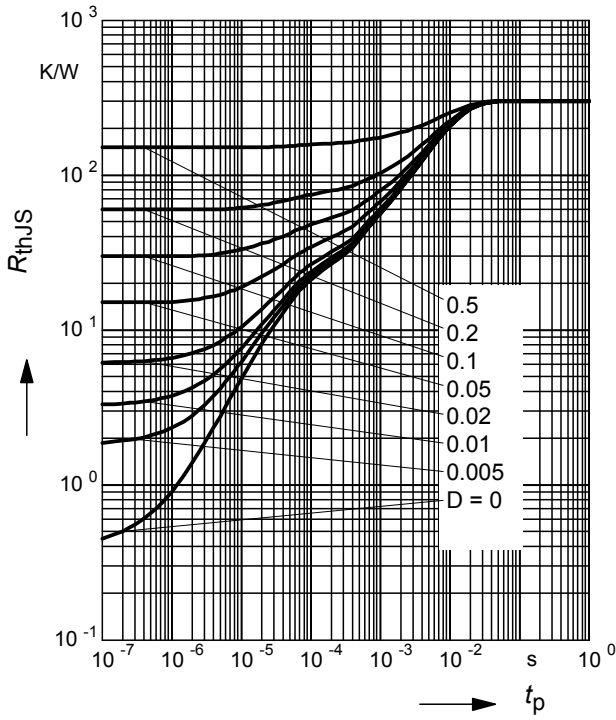
$P_{totmax}/P_{totDC} = f(t_p)$

BCR191W



Permissible Puls Load  $R_{thJS} = f(t_p)$

SEMB1



Permissible Pulse Load

$P_{totmax}/P_{totDC} = f(t_p)$

SEMB1

